

40V +175°C P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max Tc = +25°C
401/	$25m\Omega @ V_{GS} = -10V$	-40A
-40V	45mΩ @ V <sub>GS</sub> = -4.5V	-30A

#### **Features and Benefits**

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- Low RDS(ON)—Ensures Minimal On-State Losses
- Small Form Factor Thermally Efficient Package Enables Higher
   Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Products
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMPH4025SFVWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

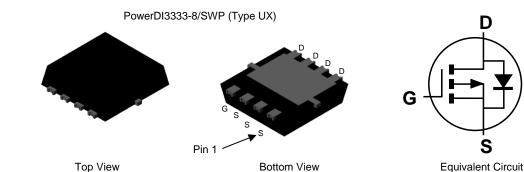
### **Description and Applications**

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Reverse-polarity protections
- Power-management functions
- DC-DC converters

#### **Mechanical Data**

- Package: PowerDI<sup>®</sup>3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (€3)
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 4)

Part Number	Package	Packing		
Fait Nulliber	Fackaye	Qty.	Carrier	
DMPH4025SFVWQ-7	PowerDI3333-8/SWP (Type UX)	2000	Tape & Reel	
DMPH4025SFVWQ-13	PowerDI3333-8/SWP (Type UX)	3000	Tape & Reel	

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

<sup>2.</sup> See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.



# **Marking Information**



 $\frac{PW1}{YY}WW = \text{Date Code Marking}$  $\frac{VY}{YY} = \text{Last Two Digits of Year (ex: 23 = 2023)}$ WW = Week Code (01 to 53)

### Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit V	
Drain-Source Voltage	VDSS	-40		
Gate-Source Voltage	V <sub>GSS</sub>	±20	V	
	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	lo	-8.7 -7.3	A
Continuous Drain Current (Note 5) V <sub>GS</sub> = -10V	T <sub>C</sub> = +25°C T <sub>C</sub> = +70°C	ID (Package Limited)	-40 -33	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	-80	A	
Maximum Continuous Body Diode Forward Current	ls	-3	A	
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)		I <sub>SM</sub>	-80	A
Avalanche Current, L = 0.3mH		las	-23	A
Avalanche Energy, L = 0.3mH		Eas	82	mJ

### **Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Tatal Power Dissipation (Nata 5)	T <sub>A</sub> = +25°C	D-	2.3	W
Total Power Dissipation (Note 5)	T <sub>C</sub> = +25°C	PD	60	W
Thermal Resistance, Junction to Ambient (Note 5) Steady State		Reja	53	°C/W
Thermal Resistance, Junction to Case (Note 5)	Rejc	2.5	C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Note: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.



# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

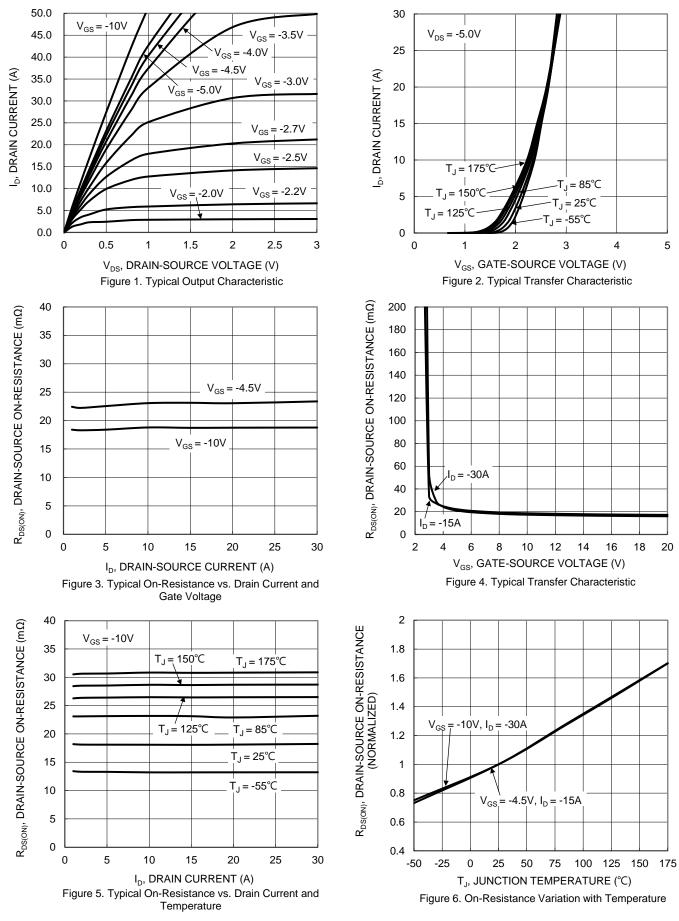
Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition	
OFF CHARACTERISTICS (Note 6)			- 71-				
Drain-Source Breakdown Voltage	BVDSS	-40			V	Vgs = 0V, Id = -250µA	
Zero Gate Voltage Drain Current	IDSS		_	-1	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 6)	·						
Gate Threshold Voltage	Vgs(th)	-0.8	_	-1.8	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Deserver	_	18	25	mΩ	V <sub>GS</sub> = -10V, I <sub>D</sub> = -30A	
Static Drain-Source On-Resistance	RDS(ON)	_	23	45		$V_{GS} = -4.5V, I_D = -15A$	
Diode Forward Voltage	Vsd	_	_	-1	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = -1A	
DYNAMIC CHARACTERISTICS (Note 7)							
Input Capacitance	C <sub>iss</sub>	_	1918	—	pF		
Output Capacitance	Coss	_	390	—	pF	− V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V − f = 1MHz	
Reverse Transfer Capacitance	Crss	_	151	_	pF		
Gate Resistance	Rg	_	5.76		Ω	V <sub>DS</sub> = 0V, V <sub>GS</sub> = 0V, f = 1MHz	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	19.6	_	nC	V <sub>DS</sub> = -20V, I <sub>D</sub> = -3A	
Total Gate Charge (V <sub>GS</sub> = -10V)	Qg	_	38.6	_	nC		
Gate-Source Charge	Qgs		3.7	_	nC		
Gate-Drain Charge	Q <sub>gd</sub>	_	7.3		nC		
Turn-On Delay Time	tD(ON)	_	4.8		ns		
Turn-On Rise Time	tR		14.2		ns	V <sub>DD</sub> = -20V, V <sub>GS</sub> = -10V	
Turn-Off Delay Time	tD(OFF)	_	72.2		ns	I <sub>D</sub> = -3A	
Turn-Off Fall Time	tF	_	35.9		ns	1	

 Notes:
 6. Short duration pulse test used to minimize self-heating effect.

 7. Guaranteed by design. Not subject to product testing.



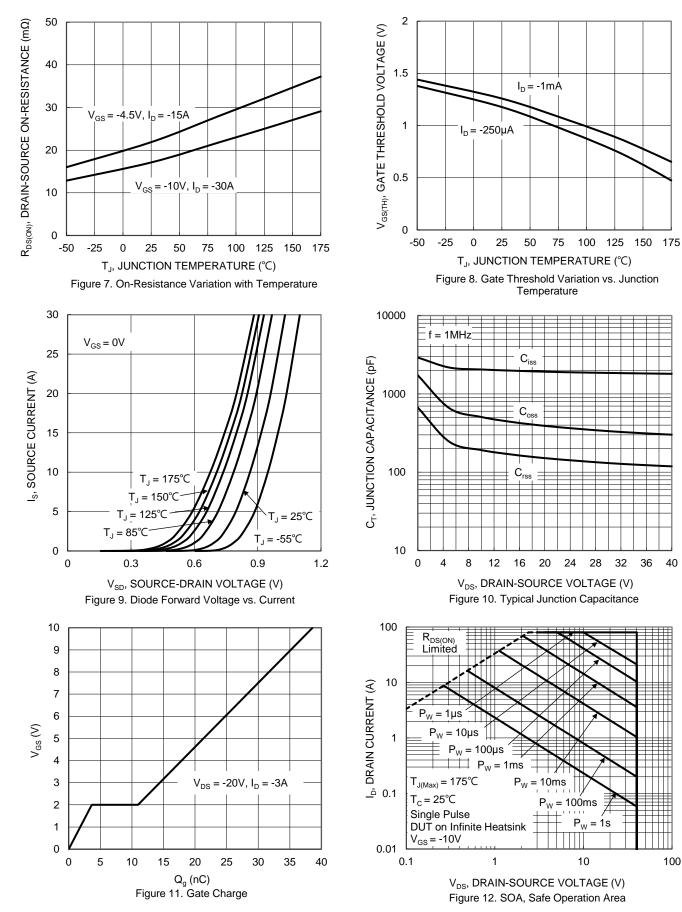
## DMPH4025SFVWQ



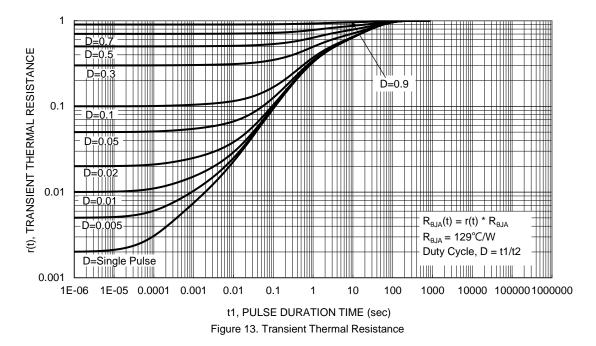
DMPH4025SFVWQ Document number: DS39847 Rev. 7 - 2



# DMPH4025SFVWQ



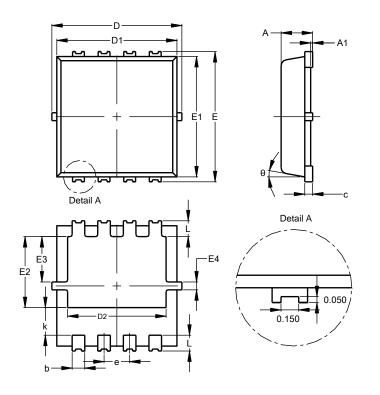






## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



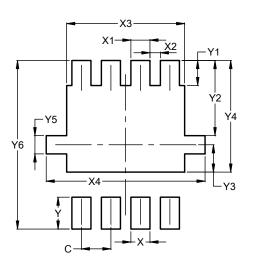
#### PowerDI3333-8/SWP (Type UX)

PowerDI3333-8/SWP					
(Type UX)					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05			
b	0.25	0.40	0.32		
С	0.10	0.25	0.15		
D	3.20	3.40	3.30		
D1	2.95	3.15	3.05		
D2	2.30	2.70	2.50		
Е	3.20	3.40	3.30		
E1	2.95	3.15	3.05		
E2	1.60	2.00	1.80		
E3	0.95	1.35	1.15		
E4	0.10	0.30	0.20		
е	_	_	0.65		
k	0.50	0.90	0.70		
L	0.30	0.50	0.40		
θ	0°	12°	10°		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### PowerDI3333-8/SWP (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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